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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/757,965	01/10/2001	Tak Hung Ning	YOR920000588US2	9386
75	590 11/20/2002			
Robert M. Trepp Intellectual Property Law Dept. IBM Corporation			EXAMINER	
			TRAN, THIEN F	
P.O. Box 218 Yorktown Heights, NY 10598			ART UNIT	PAPER NUMBER
2 020	,		2811	
			DATE MAILED: 11/20/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	09/757,965	NING, TAK HUNG				
^ Office Action Summary	Examiner	Art Unit				
	Thien F Tran	2811				
The MAILING DATE of this communication appears on the cov r sh t with th correspond nce address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status						
1) Responsive to communication(s) filed on						
2a) ☐ This action is FINAL . 2b) ☑ Thi	s action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213. Disp sition of Claims						
4)⊠ Claim(s) <u>1-22</u> is/are pending in the application.						
4a) Of the above claim(s) <u>3,4 and 6-22</u> is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1,2 and 5</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or	election requiremen	t.				
Application Papers						
9)☐ The specification is objected to by the Examiner.						
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) ☐ All b) ☐ Some * c) ☐ None of:						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) The translation of the foreign language provisional application has been received. 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 8.	5) 🔲 Not	rview Summary (PTO-413) Paper No(s) ce of Informal Patent Application (PTO-152) er:				

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DETAILED ACTION

Election/Restrictions

Applicant's election without traverse of claims 1, 2, 5 in Paper No. 5 and 7 is acknowledged.

Claims 6, 8, 10 and 11 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected species, there being no allowable generic or linking claim. Election was made **without** traverse in Paper No. 5.

Claim Rejections - 35 USC § 112

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

Claims 1, 2 and 5 are rejected under 35 U.S.C. 112, first paragraph, as based on a disclosure which is not enabling. The electrical potentials and the thickness of the collector region which are critical or essential to the practice of the invention, but not included in the claim(s) is not enabled by the disclosure. See *In re Mayhew*, 527 F.2d 1229, 188 USPQ 356 (CCPA 1976). The lightly doped region of the collector is fully depleted when the following variables are met, the proper electrical potentials applied to the device (proper base-collector reverse bias such as 3 V), the right amount of dopant concentration such as 2x10¹⁷ cm⁻³ in the lightly doped region of the collector, and the right thickness of the collector region such as 160 nm. Claiming only the dopant concentration in the lightly doped region of the collector in claim 1 without the

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proper base-collector reverse bias and the collector thickness is not sufficient for the lightly doped region of the device to be fully depleted of mobile charge.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1 and 2, insofar as in compliance with 35 USC 112, are rejected under 35 U.S.C. 102(b) as being anticipated by Mahnkopf et al. (USPN 5,587,599).

Mahnkopf et al. discloses the claimed bipolar transistor (Fig. 5) comprising a substrate, an insulating layer over said substrate, a first single crystal semiconductor layer positioned over said insulating layer having a lightly doped region 22 of a first type and at least one contiguous heavily doped region 10 of said first type, said lightly doped region and said contiguous heavily doped region functioning as a collector, a second patterned semiconductor layer 21 of a second type formed over said lightly doped region of said first semiconductor layer to function as the base, and a third patterned semiconductor layer (5, 8) of said first type positioned over said second semiconductor layer to function as the emitter, said lightly doped region 22 of said first type having a light doping that the collector region 22 is essentially completely depleted of mobile charge through said first semiconductor layer to said insulating layer when the electrical potentials required for the intended operating mode of the transistor are applied.

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Regarding claim 2, the first single crystal semiconductor layer 22 has a thickness in the range from 30 to 1000 nanometers.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 5, insofar as in compliance with 35 USC 112, is rejected under 35 U.S.C. 103(a) as being unpatentable over Mahnkopf et al. (USPN 5,587,599) in view of Imai (USPN 5,506,427).

Mahnkopf et al. as described above does not explicitly disclose the second patterned semiconductor layer 21 (the base layer) being a silicon germanium alloy. Imai discloses a bipolar transistor in which the base is formed of silicon germanium alloy. It would have been obvious to a person having ordinary skill in the art at the time the invention was made to form the base layer 21 of Mahnkopf et al. of silicon germanium alloy to enhance the efficiency of carrier injection from the emitter into the base.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thien F Tran whose telephone number is (703) 308-4108. The examiner can normally be reached on 8:00AM - 4:30PM Monday through Friday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (703) 308-2772. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9318 for regular communications and (703) 872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

tt November 18, 2002

Thien Tran
Patent Examiner
Technology Center 2800